



### **60V P-Channel Enhancement Mode MOSFET**

Voltage

-60 V

Current

-12 A

#### **Features**

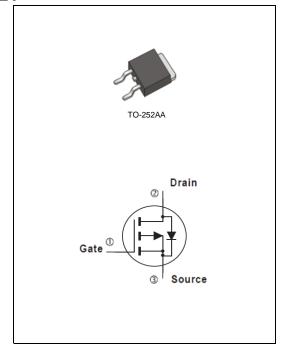
- $R_{DS(ON)}$ ,  $V_{GS}@-10V$ , $I_D@-6A<155m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: TO-252AA Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0104 ounces, 0.297grams



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub> -60			
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current (Note 4)	T <sub>C</sub> =25°C	l <sub>D</sub>	-12	A	
	T <sub>C</sub> =100°C		-7.7		
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	-48		
Power Dissipation	T <sub>C</sub> =25°C	1	50	10/	
	T <sub>C</sub> =100°C	Po	20	W	
Continuous Drain Current	T <sub>A</sub> =25°C	l <sub>D</sub>	-2.6	•	
	T <sub>A</sub> =70°C		-2	Α	
Power Dissipation	T <sub>A</sub> =25°C	Po	2	144	
	T <sub>A</sub> =70°C		1.3	W	
Single Pulse Avalanche Energy (Note 6)		E <sub>AS</sub>	337	mJ	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ heta JC}$	2.5	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

Limited only By Maximum Junction Temperature





### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250uA	-60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$		-2	-2.86	-4	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-6A	-	132	155	mΩ
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =-60V, $V_{GS}$ =0V	-	-	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-48V, I <sub>D</sub> =-12A, V <sub>GS</sub> =-10V <sup>(Note 2,3)</sup>	-	10.9	-	nC
Gate-Source Charge	$Q_gs$		-	2.7	-	
Gate-Drain Charge	$Q_{gd}$		-	4	-	
Input Capacitance	Ciss	$V_{DS}$ =-25V, $V_{GS}$ =0V, $f$ =1MHZ	-	385	-	pF
Output Capacitance	Coss		-	158	-	
Reverse Transfer Capacitance	Crss		-	31	-	
Turn-On Delay Time	td <sub>(on)</sub>	\/ 00\/ I 40A	-	4.4	-	ns
Turn-On Rise Time	t <sub>r</sub>	$V_{DS}$ =-30V, $I_{D}$ =-12A, $V_{GS}$ =-10V, $R_{G}$ =6 $\Omega$ (Note 2.3)	-	59	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	20	-	
Turn-Off Fall Time	t <sub>f</sub>		-	36	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	I <sub>S</sub>		_	-	-12	А
Diode Forward Current		1 441/ 01/		0.75		<u> </u>
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-1A,V <sub>GS</sub> =0V	-	-0.75	-1	V
Reverse Recovery Time	trr	V <sub>GS</sub> =0V, I <sub>S</sub> =-12A	-	37	-	ns
Reverse Recovery Charge	Qrr	dI <sub>F</sub> / dt=100A/us (Note 2)	-	67	-	nC

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 4. The maximum current rating is package limited.
- 5. Roja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. L=3mH,  $I_{AS}$ =-15A,  $V_{GS}$ =-10V,  $V_{DS}$ =-25V,  $R_{G}$ =25 ohm, Starting  $T_{J}$ =25°C.
- 7. Guaranteed by design, not subject to production testing.





#### TYPICAL CHARACTERISTIC CURVES

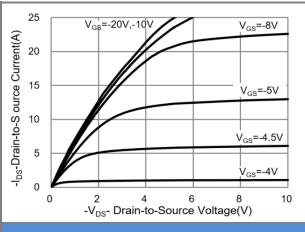
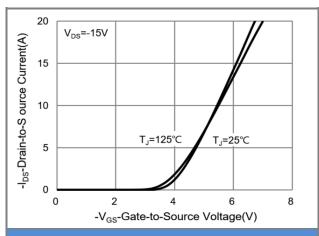


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

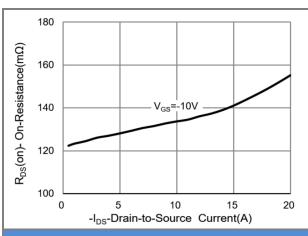


Fig.3 On-Resistance vs. Drain Current

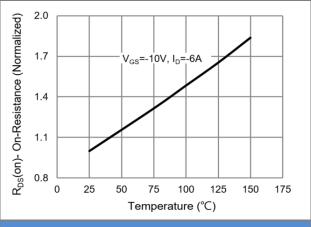


Fig.4 On-Resistance vs. Junction temperature

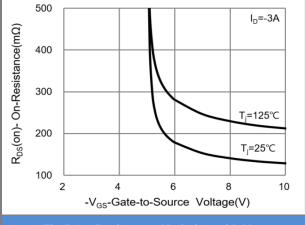


Fig.5 On-Resistance Variation with V<sub>GS</sub>

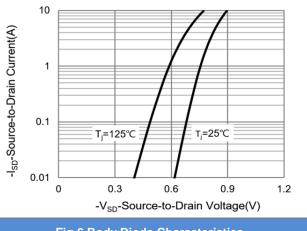


Fig.6 Body Diode Characteristics





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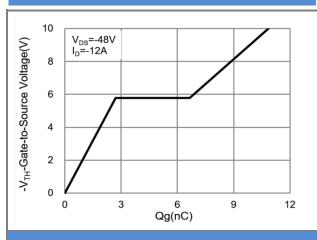


Fig.7 Gate-Charge Characteristics

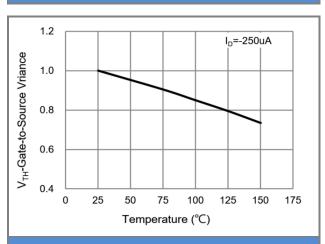
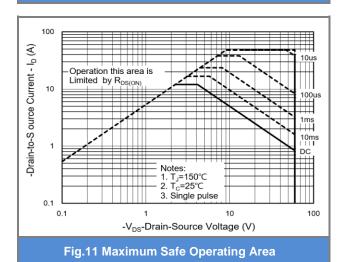


Fig.9 Threshold Voltage Variation with Temperature



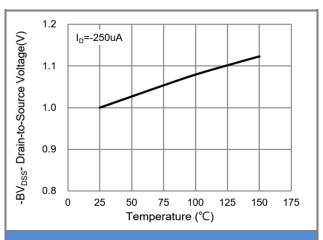


Fig.8 Breakdown Voltage Variation vs. Temperature

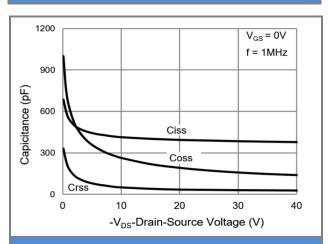
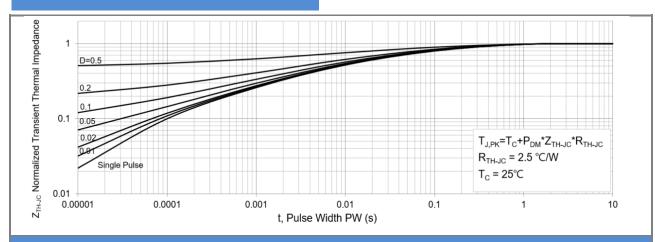


Fig.10 Capacitance vs. Drain-Source Voltage





#### **TYPICAL CHARACTERISTIC CURVES**



**Fig.12 Normalized Thermal Transient Impedance** 

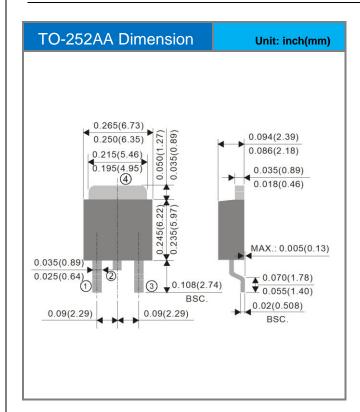


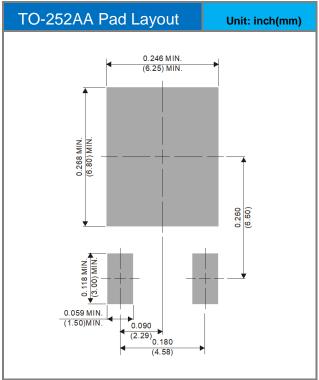


#### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJD12P06-AU_L2_000A1	TO-252AA	3,000pcs / 13" reel	D12P06	Halogen free

### **Packaging Information & Mounting Pad Layout**









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